





Nanostructured Interfaces and Surfaces Centre of Excellence www.nis.unito.it

## Monday 13 and Tuesday 14 December 2004 Dipartimento di Fisica Sperimentale, Via Pietro Giuria 1, Torino

## Scanning Probe Microscopy and Nanotechnology

### Monday 13 – Aula Magna

- 14.30 14.45 Claudio Manfredotti Introduction
   *NIS Torino (I)* 
   14.50 - 15.30 Alexander Shlüger – Measuring the force of individual surface ions
- III.00 IS.00 Alexander bindger Measuring the force of individual surface forts University College London (UK)
   I5.30 - 16.10 Florence Marchi - Atomic Force Microscopy and related techniques:

### BREAK

 16.40 - 17.20 Paolo Samorì - Scanning probe microscopies beyond imaging ISOF - CNR Bologna (I)
 17.20 - 18.00 Serena Bertarione - Imaging the surface morphology on nanostructured

materials by atomic force microscopy <u>NIS Torino (I)</u>

new ways and tools to explore the nanoworld

University of Grenoble, UJF-LEPES/CNRS (F)

## Tuesday 14 – Aula A

<b>9.00 - 9.40</b>	<mark>Ugo Valbusa</mark> – The nanostructure zoo
	Università di Genova (I)
■ 9.40 - 10. <del>2</del> 0	Giorgio Mori – Chemical and transport properties
	of nanostructures fabricated
	by local anodic oxidation
	INFM - TASC Trieste (I)
<b>10.20 - 11.00</b>	Chiara Manfredotti – Nanofunctionalization
	of diamond surfaces



#### BREAK

■ 11.30 - 12.10	Pasqualantonio Pingue – The Nanoworker: a user-friendly approach to SPM-based nanolithography and nanomanipulation
	NEST - LNFM Pisa (1)
■ 12.10 - 12.50	Thomas Muehl – STM-based nanolithography of diamond-like carbon films $IFW Dresden (D)$
	Il coordinatore del Centro di Eccellenza NIS
info.nis@u	nito.it Adriano Zecchina

by local anodic oxidation NIS Torino (I)

## Measuring the force of individual surface ions

### Adam S. Foster<sup>1,2</sup> Andrey Y. Gal<sup>2</sup> and Alexander L. Shluger<sup>2</sup>

<sup>1</sup> Laboratory of Physics, Helsinki University of Technology, FIN-02015, Helsinki, Finland <sup>2</sup> Department of Physics and Astronomy, University College London, Gower St., London WC1E 6BT, UK, <u>a.shluger@ucl.ac.uk</u>

Recent experiments using dynamic force microscopy (DFM) demonstrate that the short-range interaction forces can be measured selectively above chemically identified sites on surfaces of insulators. These experiments and atomically resolved DFM imaging of insulators rely on advanced theoretical models for their interpretation. We will discuss and compare the results of calculations of the tip-surface interaction and modelling of DFM imaging of insulating surfaces using different tips. The theoretical models available now are sufficiently refined to provide information not only about the surface, but also the probe tip, and the physical changes occurring during the scanning process. We will compare the mechanisms of image contrast formation on ionic and covalent surfaces and the transferability of image interpretation between surfaces of similar structure. The applications of DFM to study the structure and spectroscopic properties of surface point defects, spin ordering and molecular manipulation will be considered.

Atomic Force Microscopy and related techniques: new ways and tools to explore the nanoworld





### Florence Marchi

University of Grenoble, UJF-LEPES/CNRS, France

In the last few years, a lot of related techniques of AFM (Atomic Force Microscopy) have been developed in order to associate local topography information with physical and/or chemical properties.

With the huge development of Nanotechnology field and more precisely nanoelectronics and nanomechanics, two main AFM related techniques and improvements, present a great interest.

Firstly Electrical modes as EFM (Electric Force Microscopy), SSRM (Scanning Spreading Resistance Microscopy), SCM (Scanning Capacitance Microscopy), Kelvin mode, secondly development of specific user interface using haptic feedback as nanomanipulator or modified AFM tips.

After an introduction to these electrical modes, the first part of this seminar will focus on the characterization of electrical properties of semiconductor nanostructures, surfaces and manipulation-detection of few electric charges even single charge [1,2].

The second part will focus on two points linked to nanomechanics:

- characterization of very low forces as Casimir and Van der Waals forces which play a crucial work in the MEMS/NEMS\* behaviour thanks to modified AFM tips,

• real-time interaction with a non flat sample, a drosophilae leg which can be considered as biological MEMS, thanks to a nanomanipulator system.

\* MEMS/NEMS : Micro/Nano Electro-Mechanical System

[2]"Single electron tunneling to insulating surfaces detected by electrostatic force", L. Klein and C. Williams, APL, **81**, 4589 (2002).

[3] 'Precision Measurement of the Casimir Force from 0.1 to  $0.9 \,\mu m$ ', U. Mohideen, A. Roy, Phys.Rev.Lett.81, 4549 (1998)

[4] 'Presence: the sense of believability of inaccessible worlds' A. Luciani, D. Urma, S. Marliere, J. Chevrier, Computers & Graphics 28, 509-517 (2004)

<sup>[1]&</sup>quot;Detection of electrostatic forces with an AFM: analytical and experimental dynamic force curves in non-linear regime", R. Dianoux, F. Martins, *F. Marchi*, C. Alandi, F. Comin, J. Chevrier, Phy. Rev B, 68, 045403 (2003)

### Scanning probe microscopies beyond imaging

Dr. Paolo Samorì (Ph.D)

Istituto per la Sintesi Organica e la Fotoreattività- Consiglio Nazionale delle Ricerche via Gobetti 101, I-40129 Bologna (Italy) (samori@isof.cnr.it)

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Institut de Science et d'Ingénierie Supramoléculaires (I.S.I.S.) Université Louis Pasteur 8, allée Gaspard Monge , F-67083 Strasbourg Cedex (France)

Unraveling physico-chemical properties of molecule based architectures across a wide range of length scales represents one of the major goals of materials science. Scanning Probe Microscopies (SPMs) permit not only the imaging of surfaces, but most interestingly they also make it possible to gain insight into a variety of physical and chemical properties of molecule-based structures occurring in scales ranging from the hundreds of micrometers down to the sub-nanometer regime. Moreover they allow the manipulation of objects with a nanoscale precision, thereby making it possible to nanopattern a surface or to cast light onto the nanomechanics of complex assemblies. Thus, they can provide crucial information for the optimisation of functional materials.

My lecture will review recent progress in the use of SPMs beyond imaging on soft materials,[1] with a particular emphasis on the study of the mechanical properties of isolated polymer chains [2] as well as on the monitoring of interfacial dynamics processes such as phase segregation phenomena in a polydisperse molecular systems physisorbed at the solid-liquid [3] or solid-gas interface,[4] on the perturbation of the electronic states of molecules adsorbed at surfaces [5,6] and on the reaction chemical occurrence [7]. Moreover, the use of the SPM tip to trigger the mechano-chemical switch between two different nanostructures in a supramolecular ensemble will be discussed.[8]

[1] P. Samorí "Scanning probe microscopies beyond imaging" (Invited Feature Article) *J. Mater. Chem.* **14**, 1353 - 1366 (2004).

[2] P. Samorí, C. Ecker, I. Gössl, P.A.J. de Witte, J.J.L.M. Cornelissen, G.A. Metselaar, M.B.J. Otten, A.E. Rowan, R.J.M. Nolte, J.P. Rabe, "High shape persistence in single polymer chains rigidified with lateral hydrogen bonding networks", *Macromolecules* **35**, 5290-5294 (2002).
[3] P. Samorí, N. Severin, K. Müllen, J. P. Rabe, "Macromolecular fractionation of rod-like polymers at atomically flat solid-liquid interfaces", *Advanced Materials*, **12** (8) 579-582 (2000).
[4] P. Samorí, V. Francke, K. Müllen, J. P. Rabe, "Self-Assembly of a Conjugated Polymer: From Molecular Rods to a Nanoribbon Architecture with Molecular Dimensions", *Chemistry - A European Journal* **5** (8), 2312-2317 (1999).

[5] P. Samorí, A. Fechtenkötter, T. Böhme, F. Jäckel, K. Müllen, J.P. Rabe, "Supramolecular staircase via self-assembly of disc-like molecules at the solid-liquid interface", *Journal of the American Chemical Society*, **123**, 11462-11467 (2001).

[6] P. Samorí, N. Severin, C. Simpson, K. Müllen, J.P. Rabe, "Epitaxial composite layers of electron donors and acceptors from very large polycyclic aromatic hydrocarbons", *J. Am. Chem. Soc.* **124**, 9454-9457 (2002).

[7] P. Samorí, C. Simpson, K. Müllen, J.P. Rabe, "Ordered monolayers of graphene sheets processed from solutions via oxidative cyclodehydrogenation", *Langmuir* 18,4183-4185 (2002).
[8] P. Samorí, H. Engelkamp, P. de Witte, A.E. Rowan, R.J.M. Nolte, J.P Rabe, "Self-assembly and manipulation of crown ether phthalocyanines at the gel-graphite interface", *Angew. Chem. Int. Ed.* 40 (12), 2348-2350 (2001) and *Angew. Chem.* 113 (12), 2410-2412 (2001).

## Imaging the surface morphology on nanostructured materials by atomic force microscopy

### Domenica Scarano, Serena Bertarione Rava Rossa

Dipartimento di Chimica Inorganica, Chimica Fisica e Chimica dei Materiali, Università degli Studi di Torino, Corso M. d'Azeglio 48, 10125 Torino

In recent years an increasing interest has emerged in the investigation of the surface morphology of a variety of polycrystalline materials, in order to correlate processes and phenomena, occurring at atomic level, with the real structure of the different surfaces. Once the morphology and the structure of the exposed faces is known, a better understanding of the surface properties of the investigated systems can be obtained.

It is known that a precise knowledge of the surface atomic structure is a prerequisite for understanding and controlling the physical processes involved in many industrial applications. As a matter of fact processes like as the growth of epitaxial films on the surfaces of single crystals, the catalytic reactions on dispersed polycrystalline materials or the possibility to modify the surfaces by means of atomic/molecular manipulations are intimately connected with the structure of the underlying surfaces.

Scanning probe microscopies (SPM) have shown a relevant role in characterizing the surface morphology of a wide class of single crystals, in order to identify any type of defect interrupting the regularity of the extended faces such as steps, kinks or to define the nature and the distribution of atomic-scale defects, such point vacancies or adatoms [1,2,3].

On the contrary rare literature data concerning the application of SPM techniques in the analysis of the surfaces of polycrystalline oxides are reported. Moreover in the last years AFM has become a powerful technique for the characterization of nanoparticles and has acquired an important role in allowing to obtain the real particle morphology, including the vertical dimension. In case of analysis of phase mixtures (polycrystalline oxides supported metal particles, mixed oxides etc.), the 3D images allow to distinguish structurally non equivalent particles, the presence of clusters/aggregates on extended and regular faces, on the basis of their size (ratio of lateral and vertical dimension). Although AFM use for particles smaller than 10 nm is limited by the strong influence of the tip convolution, in the 10-100 nm, it gives information camparable with TEM technique.

As far as the aim of this contribution is concerned, some AFM images of polycrystalline oxides (ZnO, NiO, MgO, LaCrO3, etc.) will be discussed and compared with previously obtained SEM and HRTEM data [4,5]. In addition, high resolution images of 'smoke' MgO obtained by atomic force microscopy will be presented. These results will be correlate with the vibrational properties of the investigated materials [6].

- [1] Fukui K., Iwasawa Y., Surface Science 1999, 441, 529.
- [2] Sangwal K., Sanz F., Gorostiza P., Surface Science 1999, 424, 139.
- [3] Barth C., Reichling M., Nature 2001, 414, 54.

[4] Scarano D., Spoto G., Bordiga S., Zecchina A., Lamberti C., Surface Science **199**2, 276, 281;

Bertarione Rava Rossa S., *PhD thesis* **2003** 

[5] Escalona Platero E., Scarano D., Zecchina A., Meneghini G., De Franceschi R., *Surface Science* **1996**, *35*0, 113; Borasio M., *degree thesis* **2001**.

[6] D.Scarano, S.Bertarione, F.Cesano, G.Spoto and A.Zecchina, "Imaging polycrystalline and smoke MgO surfaces with atomic force microscopy: a case study of high resolution image on a polycrystalline oxide" *Surface Science* **570** (2004) 155-166.

### The nanostructure zoo

### Ugo Valbusa

### Dipartimento di Fisica and INFM Università di Genova, Via Dodecaneso 33, 16136 Genova Italy

By using ion erosion and molecular beam hepitaxy a large variety of nanostructures have been obtained. Quantum dots (1), magnetic wires (2), ripples (3), checkerboards (4), simple (5) and rhomboidal pyramids (6) have been observed in several materials ranging from semiconductors to metals, from glasses to ionic crystals.

The talk will review the elementary mechanisms which are at the base of these phenomena and will illustrate the potential applicability of these techniques in nanotechnology.

- 1) Facsko et al. Science **285**, 1551 (1999).
- 2) Moroni et al. PRL **91**, 167207, (2003)
- 3) Rusponi et al. PRL **78**, 2795 (1997), Costantini et al. PRL **84**, 2445, (2000)
- 4) Costantini et al. PRL **86**, 838, (2001)
- 5) Buatier et al. PRL **91**, 016102, (2003) AIP Physics News **643** June (2003) Zhu et al. PRL **92**,
- 106102 (2004). (2004), Fichthorn and Scheffler, Nature  $~{\bf 429},\,585,\,(2004)$
- 6) Molle et al. PRL in press

## Chemical and transport properties of nanostructures fabricated by local anodic oxidation

<u>G. Mori</u>,<sup>1,2</sup> M. Lazzarino,<sup>1</sup> S. Heun,<sup>1</sup> D. Ercolani,<sup>1,3</sup> G. Biasiol, <sup>1</sup> and L. Sorba<sup>1,3</sup>

<sup>1</sup>Laboratorio Nazionale TASC-INFM, I-34012 Trieste, Italy. <sup>2</sup> Università degli Studi di Trieste, I-34127 Trieste, Italy. <sup>3</sup> Università degli Studi di Modena e Reggio Emilia, I-41100 Modena, Italy.

Local anodic oxidation (LAO) is an effective tool for patterning the surface of a conductive sample. In last years, LAO lithography has been employed with success for the definition of mesoscopic devices on GaAs/AlGaAs heterostructures as quantum point contacts (QPCs),<sup>1</sup> quantum dots<sup>2</sup>, and Aharonov-Bohm rings.<sup>3</sup> On the other hand only few works have been dedicated to the study of the chemical properties of the LAO-oxides.<sup>4-7</sup> This type of knowledge represents the first step in order to control the chemistry of the LAO-oxides.

In this presentation the attention will be focused on the transport and chemical properties of nanostructures fabricated with LAO. In particular, a QPC has been fabricated with LAO on a high mobility GaAs/AlGaAs two dimensional electron gas.<sup>1</sup> At low temperature the QPC shows well defined plateaus due to the conductance quantization. We investigated also the evolution of the conductance plateaus as a function of perpendicular magnetic field and found that the observed behavior well agrees with the one predicted by the model of Berggren et al.<sup>8</sup>

The chemical properties of the LAO nanostructures have been investigated with microscopic X-ray photoemission spectroscopy.<sup>7</sup> We find that the LAO-structures desorb under irradiation with soft X-rays (130 eV). We analyzed the desorption process by time-resolved photoelectron spectroscopy. We observe that even in the first stages of light exposure LAO-oxide is mainly composed of  $Ga_2O$ , with a small fraction of  $Ga_2O_3$  and As-oxides. The As-oxides are located only in the surface layers of the LAO-oxide where they account for 10 % of the oxide. Moreover, we find evidence for the presence of unoxidized GaAs in the LAO-oxide.

<sup>1</sup>G. Mori, M. Lazzarino, D. Ercolani, G. Biasiol, and L. Sorba, J. Vac. Sci. Technol. B **22** (2), 570 (2004).

<sup>2</sup>S. Luescher, A. Fuhrer, R. Held, T. Heinzel, K. Ensslin, and W. Wegscheider, Appl. Phys. Lett. **75**, 2452 (1999).

<sup>3</sup>A. Fuhrer, S. Luescher, T. Ihn, T. Heinzel, K. Ensslin, W. Wegscheider, and M. Bichler, Nature **413** (6858), 822 (2001).

<sup>4</sup>Y. Okada, Y. Iuchi, M. Kawabe, and J. S. Harris, J. Appl. Phys. **88** (2), 1136 (2000).

<sup>5</sup>D. Ercolani, M. Lazzarino, G. Mori, B. Ressel, L. Sorba, A. Locatelli, S. Cherifi, A. Ballestrazzi, and S. Heun, Advanced functional materials, in press, (2004).

<sup>6</sup>M. Lazzarino, S. Heun, B. Ressel, K. C. Prince, P. Pingue, and C. Ascoli, Appl. Phys. Lett. **81** (15), 2842 (2002).

<sup>7</sup>G. Mori, M. Lazzarino, D. Ercolani, L. Sorba, and Heun S., submitted to J. Appl. Phys., (2004).

<sup>8</sup>K. F. Berggren, T. J. Thornton, D. J. Newson, and M. Pepper, Phys. Rev. Lett. **57**, 1769 (1986).

## Nanofunctionalization of diamond surfaces by local anodic oxidation

### Chiara Manfredotti

Experimental Physics Department and Centre of Excellence "Nanostructured Interfaces and Surfaces", University of Torino, Via P. Giuria 1, I-10125 Torino, Italy <u>chiara.manfredotti@to.infn.it</u>

Diamond shows surface properties no other material shows; these properties differ largely as the top surface layer is H- or O-terminated (1). A H-terminated surface has a high p-type conductivity in undoped diamond also (holes concentration is about  $10^{13}$  cm<sup>-2</sup> for some nanometres depth), is highly hydrophobic and is characterized by negative electron affinity (NEA), while an O- terminated surface is insulating (resistivity is about  $10^{11}$  ohm cm), hydrophilic, and shows a normal electron affinity (PEA). It has been demonstrated that a FET structure can be realized by using the surface conductive layer; moreover, these diamond properties can be utilized for biosensing applications (2,3).

The oxidation of a H-terminated surface at a nanometre scale can be obtained by local anodic oxidation (LAO), using an atomic force microscope (AFM) in contact mode and a conductive tip by applying some volts biases to the sample surface. In such a way, MOS lateral structures (4) have been realized, having an 'oxidized' line 60 nm wide through which the tunneling Fowler-Nordheim mechanism has been observed.

The oxidation of the diamond hydrogenated surface as a function of different parameters like scan speed, ambient humidity and applied bias (5,6) has been investigated, using a homoepitaxial diamond sample, composed by an Ib type HPHT diamond, (100) oriented, onto which an IIa type diamond film (5  $\mu$ m wide) has been epitaxially grown.

Results indicate a good reproducibility of the oxidation lines, the width of which at scan speeds lying between 20 e 110 nm/s, varies from 80 to 100 nm and from 45 to 90 nm at 60% and 40% ambient humidity respectively. The oxidation process is accompanied by a current decay between tip and sample that ends in about 10 s.

Other investigations are necessary in order to define clear conclusions on the nature of the chemical reaction responsible of the phenomenon, that cannot be simply interpreted as an analogue of what happens e.g. on silicon. Moreover, some aspects of surface topographic variations accompanying the process must be cleared, as about that nonconforming data are present in literature.

- (1) F. Maier, L. Ley et al., 'Origin of Surface Conductivity in Diamond', Phys. Rev. Lett. 85, (2000), 3472.
- (2) M. Tachiki, Y. Kaibara, Y. Sumikawa *et al.*, 'Diamond nanofabrication and characterization for biosensing applications', Phys. Stat. Sol. (a) **199**, (2003), 39.
- (3) A. Härtl, E. Schmich, J. A. Garrido *et al.*, ,'Protein-modified nanocrystalline diamond thin films for biosensor applications', *Nature Mater.* **3**, (2004), 736.
- (4) M. Tachiki, H. Umezawa, H. Kawarada *et al.*, 'Control of adsorbates and conduction on CVDgrown diamond surface, using scanning probe microscope', *Appl. Surf. Sci.* **159-160**, (2000), 578.
- (5) C. Manfredotti, E. Vittone, C. Paolini, L. Bianco, F. Fizzotti, A. Lo Giudice, P. Olivero, 'Control of hydrogenation patterning for CVD diamond surfaces by AFM Local Anodic Oxidation', *Surface Eng.* **19** (6), (2003), 441.
- (6) C. Manfredotti *et al.*, 'Surface patterning and functionalization by local anodic oxidation on CVD diamond', International Conference on Advances in Surface Treatment: Research and Applications, Hyderabad (India), November 2003

# The *Nanoworker*: a user-friendly approach to SPM-based nanolithography and nanomanipulation

P. Pingue<sup>(a)</sup>, P. Baschieri<sup>(b)</sup>, C. Ascoli<sup>(b)</sup>, M. Dayez<sup>(c)</sup>

<sup>(a)</sup>Laboratorio NEST-INFM, Scuola Normale Superiore, Piazza dei Cavalieri 7, 56126 Pisa (Italy); <u>pingue@nest.sns.it</u>

<sup>(b)</sup>Istituto per i Processi-Chimico Fisici del CNR (IPCF – CNR), Area della Ricerca di Pisa, Via G. Moruzzi 1, 56124 Pisa (Italy)

<sup>(c)</sup>Laboratoire de Recherche sur les Mecanismes de la Croissance Cristalline (CRMC2-CNRS), Campus de Luminy, 13288 Marseille Cedex 9 (France)

A new scanning probe microscope (SPM) system has been developed and its utilization as a tool for lithography, manipulation and mapping on nanometer scale is reported. User-friendly graphic interface allows to perform nanolithography and to monitor the whole process in real time. We implemented two types of lithographic processes.

The first one is VECTORIAL MODE: mouse leads the tip upon the surface, in the three spatial dimensions. In vectorial mode we import the acquired image in the "Vectorial window", and then we move the mouse upon the image, acting the probe in real time as a pantograph from macroscopic down to nanometer scale, taking advantage from an absolute-positioning stage. We can also select any parameter (i.e. applied force, or tip-surface bias) and applying it locally by a mouse click or tuning it by the mouse scroller. Moreover, the so called "*contour-mode*" allows turning off the feedback, moving the tip in any direction at a fixed relative tip-sample distance, taking in account sample topography. Finally, vectorial mode can also be performed in automatic mode, repeating several times a previously-saved lithographic process.

The second one is SMART-BITMAP MODE: this configuration allows superimposing a bitmap pattern, with 24bit-resolution colour table, on a selected region of the previously-imaged sample region. Three different lithographic tasks are assigned to the 3 (RGB) colour scales, with 256 values each. Lithography is performed in FORWARD scan and imaged in BACKWARD scan. For example, we can plan to perform on forward scan force-distance maps with different dwell times related to the red scale of the bitmap image, applying a force modulated by the green scale and a voltage modulated by the blue tones.

The instrument has been successfully employed in order to perform dynamic ploughing<sup>1</sup>, spatially-resolved anodization lithography  $(LAO)^2$  on semiconductor and metallic substrates, dip-pen nanolithography  $(DPN)^3$  and carbon nanotubes manipulation. Any measured properties of the sample can be used by a new and user-friendly lithographic interface to realize interactive patterning of the sample. Other interesting applications of this instrument in nanolithography will be also presented.

<sup>&</sup>lt;sup>1</sup>T.A. Jung, A. Moser, H.J. Hug, D.Brodbeck, R. Hofer, H.R. Hidber and U.D. Schwarz, *Ultramicroscopy* **42-44**, 1446(1992);

<sup>&</sup>lt;sup>2</sup> J. A. Dagata, J. Schneir, H. H. Harary, C. J. Evans, M. T. Postek, and J.Bennett, *Appl. Phys. Lett.* **56**, 2001(1990);

<sup>&</sup>lt;sup>3</sup> Richard D. Piner, Jin Zhu, Feng Xu, Seunghun Hong, Chad A. Mirkin, *Science* 283, 661(1999).

## STM-based nanolithography of diamond-like carbon films

### Thomas Muehl

### Leibniz Institute for Solid State and Materials Research Dresden (IFW Dresden), Helmholtzstr. 20, D-01069 Dresden, Germany

The spatially localized emission current of a scanning tunnelling microscope tip leads to the local oxidation or the local graphitization of diamond-like carbon thin films depending on whether the environment is air or ultrahigh vacuum, respectively. Using this technique, nanostructures smaller than 10 nm can be written.

Due to the different properties of diamond-like and graphite-like carbon, there are a lot of possible applications for graphite nanostructures on diamond films. Systematic investigations of the current, voltage and charge dependence combined with analytical methods like scanning tunnelling spectroscopy and conductive scanning force microscopy provide some preliminary conclusions on the underlying modification mechanism on an atomic scale.



Fig.: STM image of graphite-like nanodots within a diamond-like carbon layer (image size 1.2  $\mu m \ge 1.2 \, \mu m$ ).

## Workshop participants

### Claudio Manfredotti

Experimental Physics Department and Centre of Excellence "Nanostructured Interfaces and Surfaces" University of Torino Via P. Giuria 1, I-10125 Torino, Italy <u>manfredotti@to.infn.it</u>

### Domenica Scarano

I.F.M. Chemistry Department and Centre of Excellence "Nanostructured Interfaces and Surfaces" University of Torino Corso M. d'Azeglio 48, I-10125 Torino, Italy <u>domenica.scarano@unito.it</u>

### Alexander L. Shluger

Department of Physics and Astronomy University College London Gower St., London WC1E 6BT, UK <u>a.shluger@ucl.ac.uk</u>

### Florence Marchi

University of Grenoble UJF-LEPES/CNRS Laboratoire LEPES-CNRS UPR 11 25, Avenue des Martyrs - BP 166 - 38042 Grenoble Cedex 9 <u>marchi@grenoble.cnrs.fr</u>

### Paolo Samorì

Istituto per la Sintesi Organica e la Fotoreattività Consiglio Nazionale delle Ricerche via Gobetti 101, I-40129 Bologna, Italy samori@isof.cnr.it

### Serena Bertarione Rava Rossa

I.F.M. Chemistry Department and Centre of Excellence "Nanostructured Interfaces and Surfaces" University of Torino Corso M. d'Azeglio 48, I-10125 Torino, Italy <u>serena.bertarione@unito.it</u>

### Ugo Valbusa

Dipartimento di Fisica and INFM Università di Genova Via Dodecaneso 33, 16136 Genova, Italy <u>valbusa@fisica.unige.it</u>

### Giorgio Mori

Università degli Studi di Trieste and Laboratorio Nazionale TASC-INFM Area di Ricerca di Trieste Basovizza, SS-14, Km 163.5 I-34012 Trieste, Italy <u>mori@tasc.infm.it</u>

### Chiara Manfredotti

Experimental Physics Department and Centre of Excellence "Nanostructured Interfaces and Surfaces" University of Torino Via P. Giuria 1, I-10125 Torino, Italy <u>chiara.manfredotti@to.infn.it</u>

### Pasqualantonio Pingue

Laboratorio NEST-INFM Scuola Normale Superiore Piazza dei Cavalieri 7, 56126 Pisa, Italy <u>pingue@nest.sns.it</u>

Thomas Muehl Leibniz Institute for Solid State and Materials Research Dresden IFW Dresden Helmholtzstr. 20, D-01069 Dresden, Germany <u>T.Muehl@ifw-dresden.de</u>